

7.5A 650V N Channel MOSFET

Features

- VDS = 650V
- ID = 7.5A @VGS = 10V
- RDS(ON) (Typ)= 1.1Ω @VGS =10V
- Low gate charge
- low crss
- fast switching

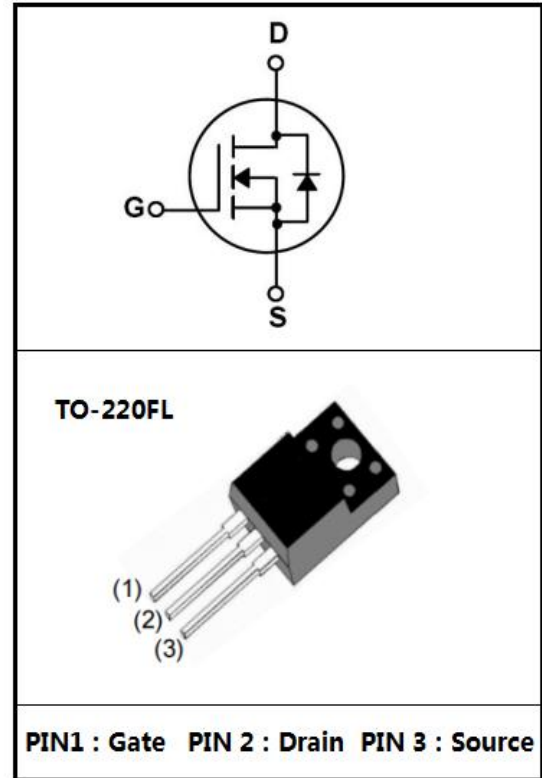
Applications

- These devices are well suited for high efficiency switching DC/DC converters, and switch mode power supplies.

Descriptions

These N-channel MOSFET are produced using advanced plane MOSFET Technology, which provides Low on-state resistance,high switching performance and excellent quality.

These devices are suitable device for SMPS,high Speed switching and general purpose applications.



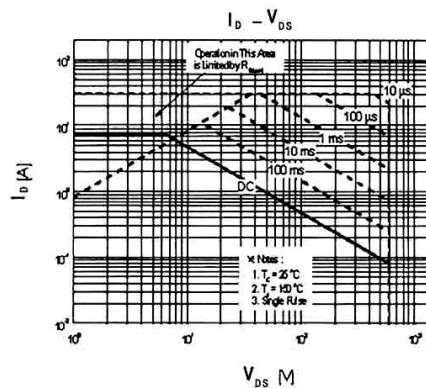
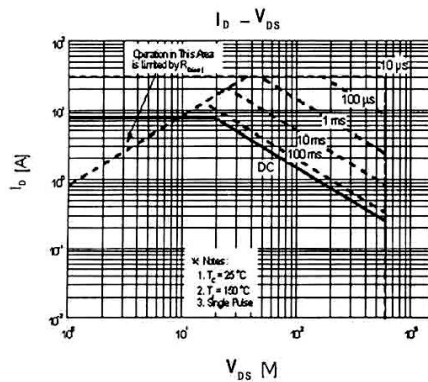
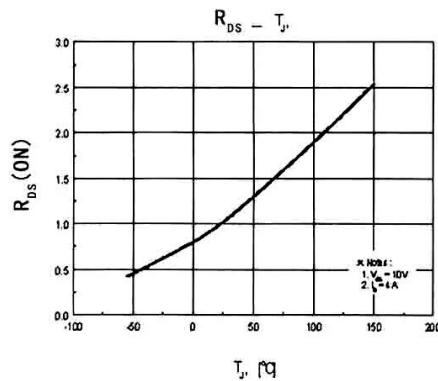
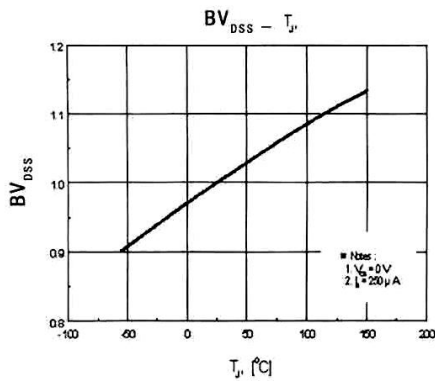
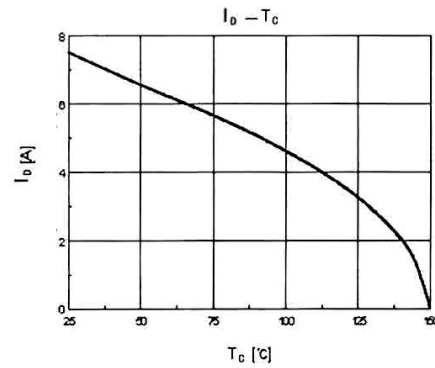
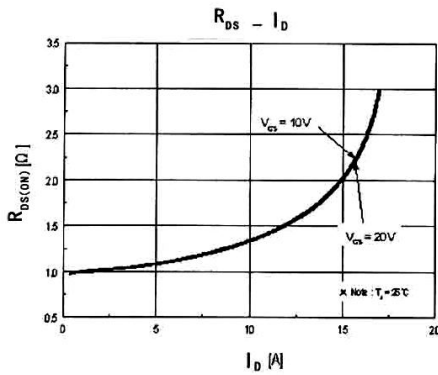
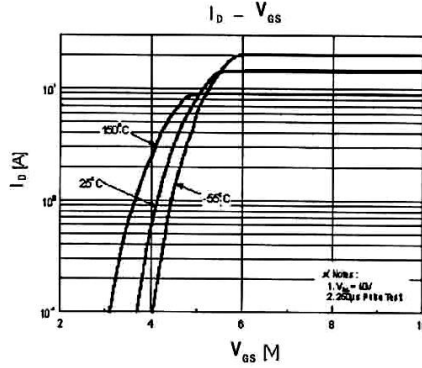
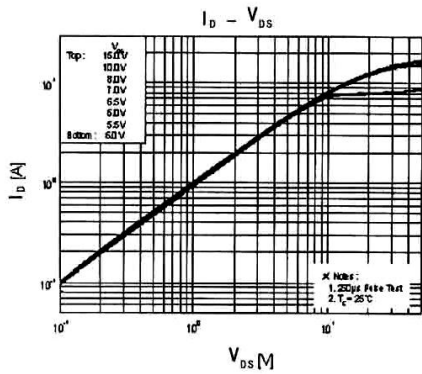
Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DSS}	650	V
Drain Current	$I_D(T_C=25^\circ\text{C})$	7.5	A
Drain Current	$I_D(T_C=100^\circ\text{C})$	4.6	A
Drain Current - Pulsed	I_{DM}	30	A
Gate-Source Voltage	V_{GSS}	±30	V
Single Pulsed Avalanche Energy	E_{AS}	230	mJ
Repetitive Avalanche Energy	E_{AR}	10	mJ
Avalanche Current	I_{AR}	7.5	A
Power Dissipation	$P_D(T_C=25^\circ\text{C})$	48	W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to 150	°C

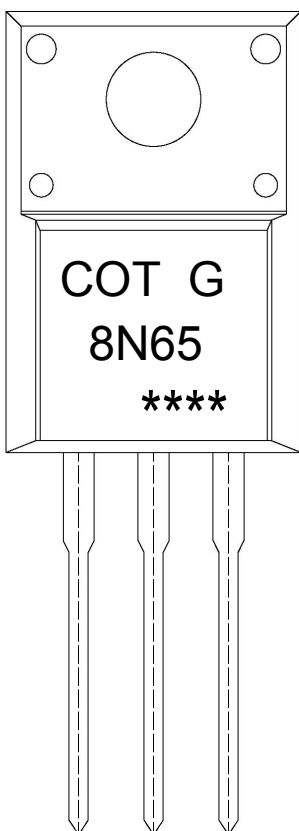
Electrical Characteristics(Ta=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=250\mu A$	650			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=650V$ $V_{GS}=0V$			1.0	μA
		$V_{DS}=480V$ $T_C=125^\circ\text{C}$			10	μA
Gate-Body Leakage Current, Forward	I_{GSS}	$V_{GS}=\pm 30V$ $V_{DS}=0V$			±0.1	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=250\mu A$	2.0		4.0	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V$ $I_D=3.75A$		1.1	1.3	Ω
Forward Transconductance	g_{FS}	$V_{DS}=40V$ $I_D=3.75A$		8.7		S
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V$ $I_S=7.5A$			1.4	V
Input Capacitance	C_{iss}	$V_{DS}=25V$ $V_{GS}=0V$ $f=1.0\text{MHz}$		965	1255	pF
Output Capacitance	C_{oss}			105	135	
Reverse Transfer Capacitance	C_{rss}			12	16	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=300V$ $I_D=7.5A$ $R_G=25\Omega$		16.5	45	ns
Turn-On Rise Time	t_r			60.5	130	
Turn-Off Delay Time	$t_{d(off)}$			81	170	
Turn-Off Fall Time	t_f			64.5	140	

Electrical Characteristic Curve



Marking Instructions



Note:

- COT: Company Logo
- G: Halogen Free
- 8N65: Product Type.
- ****: Lot No. Code, code change with Lot No.

Packaging SPEC.

TUBE

Package Type	Units					Dimension (unit: mm ³)		
	Units/Tub	Tubes/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Tube	Inner Box	Outer Box
TO-220FL	50	20	1,000	5	5,000	532×33×7.0	555×164×50	575×290×180

Package Outline Dimensions

TO-220FL

单位: mm

